



PolyZen Devices

Polymer Protected Zener Diode

PolyZen devices are polymer enhanced precision Zener diode micro-assemblies that help protect sensitive electronics from damage caused by inductive voltage spikes, voltage transients, use of incorrect power supplies and reverse bias.

The PolyZen micro-assembly incorporates a stable Zener diode for precise voltage clamping and a resistively non-linear, polymeric positive temperature coefficient (PPTC) layer that responds to either diode heating or overcurrent events by transitioning from a low to high resistance state.

PolyZen devices help provide resettable protection against damage caused by multi-watt fault events and require only 0.7W power dissipation. In the event of sustained high power conditions, the PPTC element of the device “trips” to limit current and generate voltage drop. This functionality helps protect both the Zener and the follow-on electronics, effectively increasing the diode’s power handling capacity.



Benefits

- Helps shield downstream electronics from overvoltage and reverse bias
- Trip events shut out overvoltage and reverse bias sources
- Analog nature of trip events minimize upstream inductive spikes
- Helps reduce design costs with single component placement and minimal heat sinking requirements

Features

- RoHS compliant
- Overvoltage transient suppression
- Hold currents up to 2.3A
- Time delayed, overvoltage trip
- Time delayed, reverse bias trip
- Power handling on the order of 30 watts
- Integrated device construction

Applications

- Portable media players
- Global positioning systems
- Hard disk drives 5V & 12V bus
- Solid State Drives (SSD) 5V bus
- Cellphone charger port and USB power
- Automotive peripheral input power
- DC power port protection
- Industrial handheld POS

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Figure PZ1 Typical Application Block Diagram for PolyZen Devices

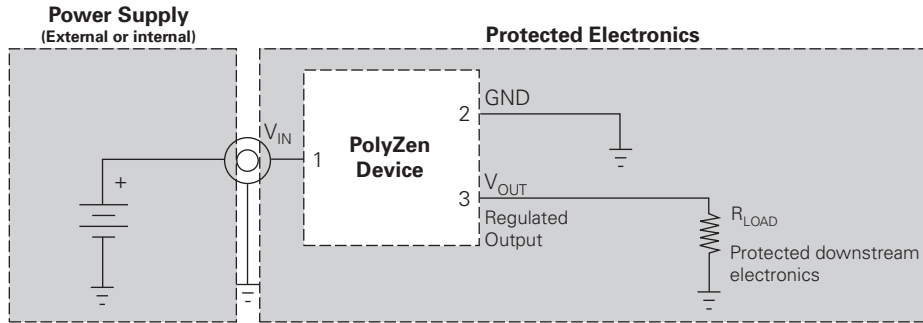


Table PZ1 Electrical Characteristics for PolyZen Devices

(Performance ratings @ 25°C unless otherwise specified)

Part Number	V _Z (V)			I _{Zt} (A)	I _{HOLD} @ 20°C (A)	R _{Typ} (Ω)	R _{1MAX} (Ω)	V _{INT MAX}		I _{FLT MAX}	
	Min.	Typ.	Max.					V _{INT MAX} (V)	Test Current (A)	I _{FLT MAX} (A)	Test Voltage (V)
ZEN056V130A24LS	5.45	5.60	5.75	0.10	1.30	0.12	0.16	24V	3A	+10/-40	+24/-16V
ZEN059V130A24LS†	5.80	5.90	6.00	0.10	1.30	0.12	0.15	24V	3A	+6/-40	+24/-16V
ZEN065V130A24LS	6.35	6.50	6.65	0.10	1.30	0.12	0.16	24V	3A	+6/-40	+24/-16V
ZEN098V130A24LS	9.60	9.80	10.00	0.10	1.30	0.12	0.16	24V	3A	+3.5/-40	+24/-16V
ZEN132V130A24LS	13.20	13.40	13.60	0.10	1.30	0.12	0.16	24V	3A	+2/-40	+24/-16V
ZEN164V130A24LS	16.10	16.40	16.60	0.10	1.30	0.12	0.16	24V	3A	+1.25/-40	+24/-16V
ZEN056V230A16LS	5.45	5.60	5.75	0.10	2.30	0.04	0.06	16V	5A	+5/-40	+16/-12V
ZEN065V230A16LS	6.35	6.50	6.65	0.10	2.30	0.04	0.06	16V	5A	+3.5/-40	+16/-12V
ZEN098V230A16LS	9.60	9.80	10.00	0.10	2.30	0.04	0.06	16V	5A	+3.5/-40	+16/-12V
ZEN132V230A16LS	13.20	13.40	13.60	0.10	2.30	0.04	0.06	16V	5A	+2/-40	+20/-12V
ZEN056V075A48LS	5.45	5.60	5.75	0.10	0.75	0.28	0.45	48V	3A	+10/-40	+48/-16V
ZEN132V075A48LS	13.20	13.40	13.60	0.10	0.75	0.28	0.45	48V	3A	+2/-40	+48/-16V
ZEN056V115A24LS	5.45	5.60	5.75	0.10	1.15	0.15	0.18	24V	3A	+10/-40	+24/-16V
ZEN056V130A24GS*	5.45	5.60	5.75	0.10	1.30	0.12	0.18	24V	3A	+6/-40	+24/-16V

* Module height is 1.25mm. Module height of all other part numbers is 2.0mm.

† Typical operating current is 500µA @ 5.0V which meets USB suspend mode requirement.

Table PZ2 Definitions of Terms for PolyZen Devices

V _Z	Zener clamping voltage measured at current I _{Zt} and 20°C.
I _{Zt}	Test current at which V _Z is measured.
I _{HOLD}	Maximum steady state current I _{PTC} that will not generate a trip event at the specified temperature. Ratings assume I _{FLT} = 0A.
R _{Typ}	Typical resistance between V _{IN} and V _{OUT} pins when the device is at room temperature.
R _{1MAX}	The maximum resistance between V _{IN} and V _{OUT} pins, at room temperature, one hour after first trip or after reflow soldering.
I _{FLT}	Current flowing through the Zener diode.
I _{FLT MAX}	Maximum RMS fault current the Zener diode component of the device can withstand and remain resettable; testing is conducted at rated voltage with no load connected to V _{OUT} .
V _{INT MAX}	The voltage (V _{IN} - V _{OUT} "post trip") at which typical qualification devices (98% devices, 95% confidence) survived at least 100 trip cycles and 24 hours trip endurance when "tripped" at the specified voltage and current (I _{PTC}).
I _{PTC}	Current flowing through the PTC portion of the circuit.
I _{OUT}	Current flowing out the V _{OUT} pin of the device.
Trip Event	A condition where the PTC transitions to a high resistance state, thereby limiting I _{PTC} , and significantly increasing the voltage drop between V _{IN} and V _{OUT} .

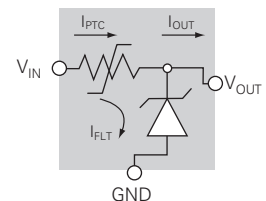
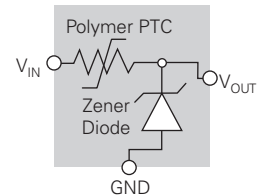


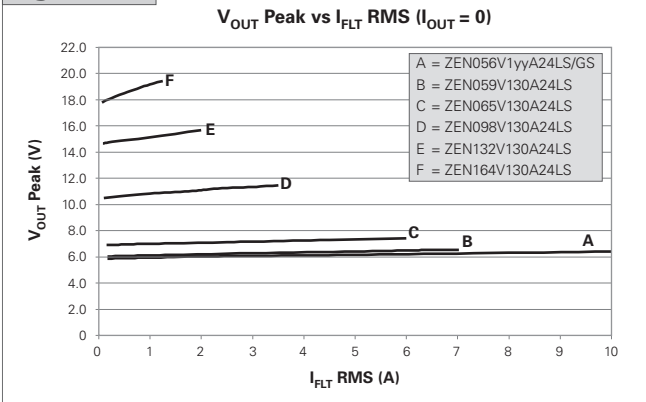
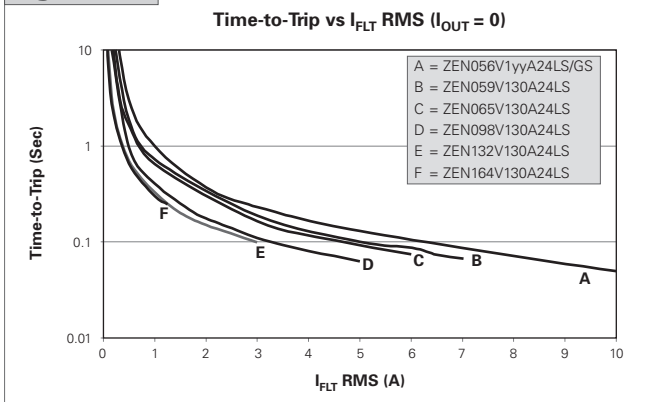
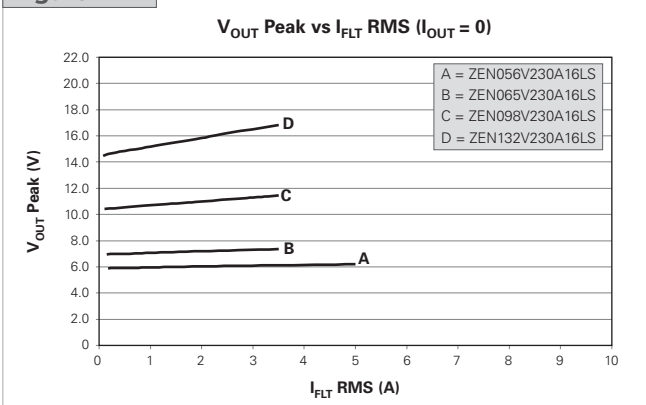
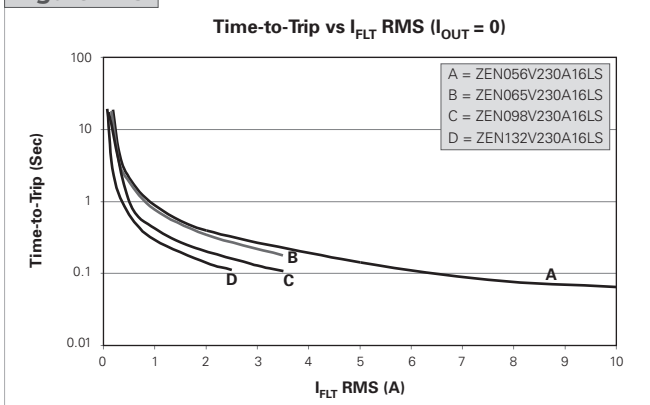
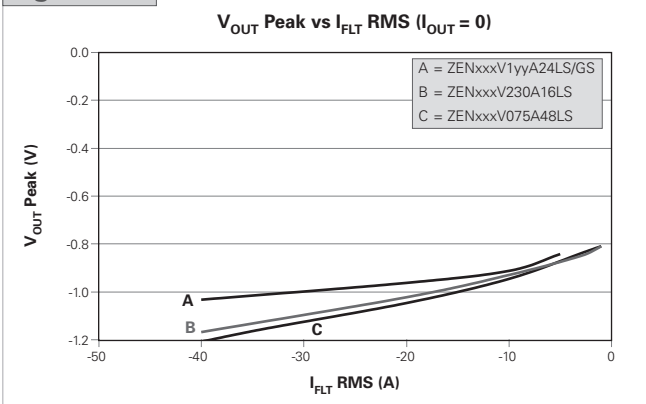
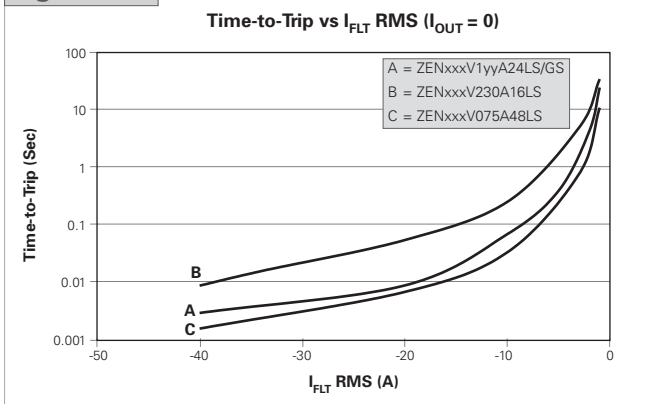
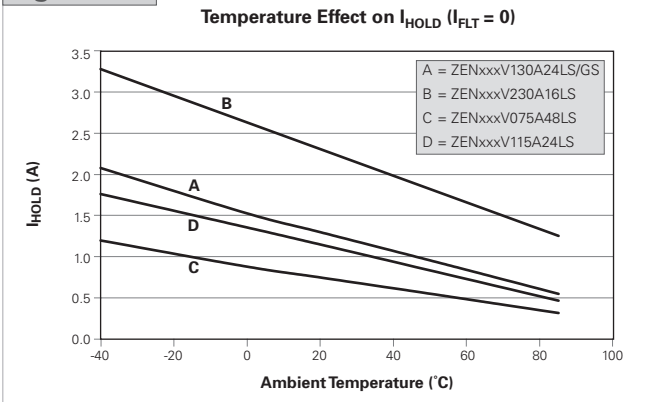
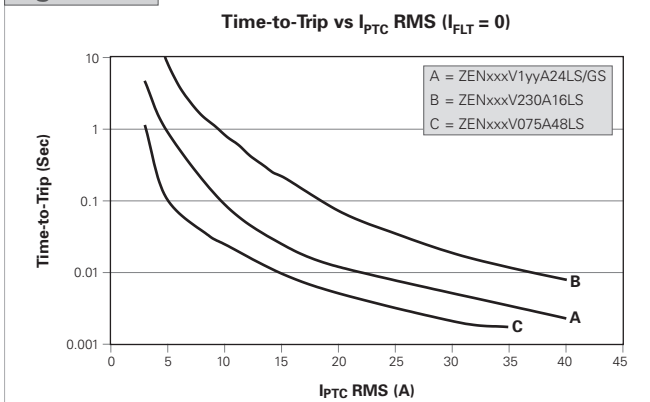
Figure PZ2-PZ9 Typical Performance Curves for PolyZen Devices
Figure PZ2

Figure PZ3

Figure PZ4

Figure PZ5

Figure PZ6

Figure PZ7

Figure PZ8

Figure PZ9


Table PZ3 General Characteristics for PolyZen Devices

Operating temperature range	-40° to +85°C	
Storage temperature	-40° to +85°C	
ESD withstand	15kV	Human body model
Diode capacitance	4200pF	Typical @ 1MHz, 1V RMS
Construction	RoHS compliant	

Figure PZ10-PZ23 Basic Operation Examples for PolyZen Devices

Figure PZ10

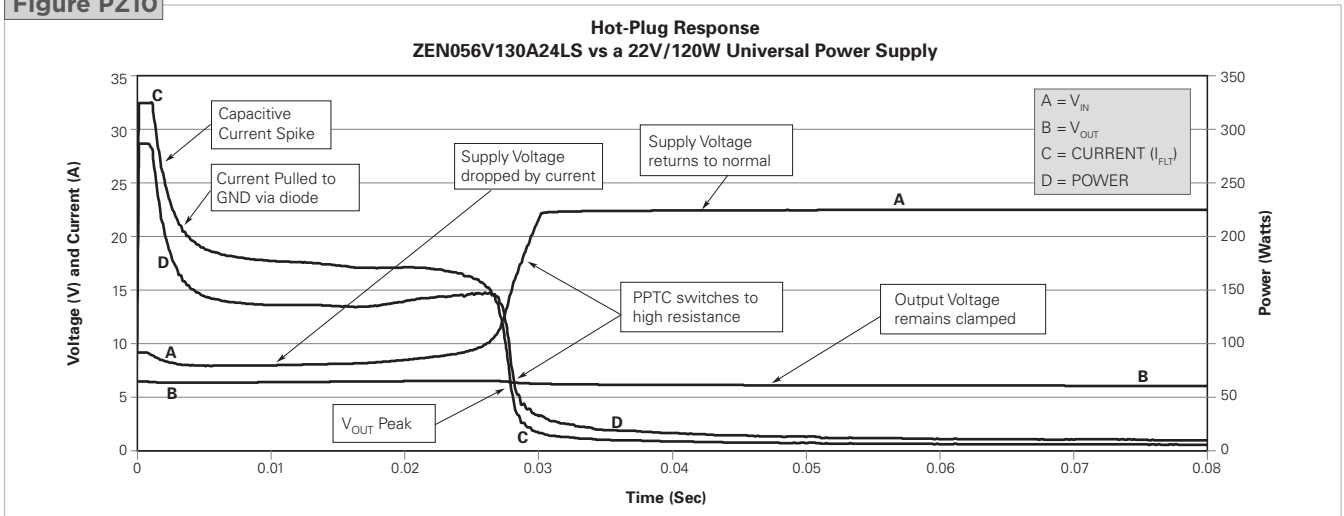


Figure PZ11

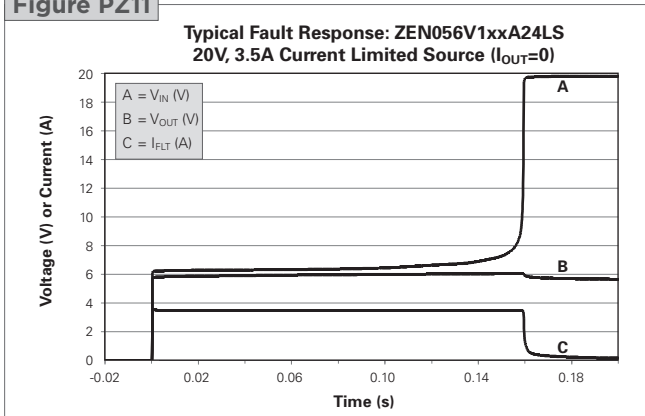


Figure PZ12

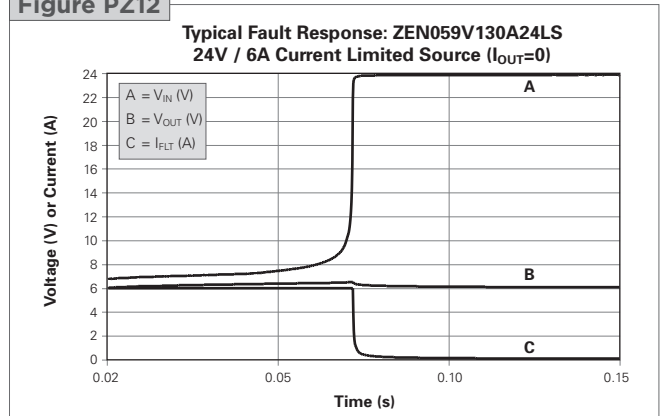


Figure PZ13

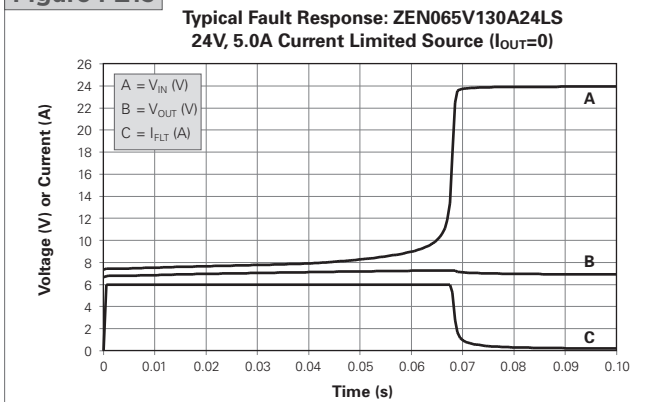


Figure PZ14

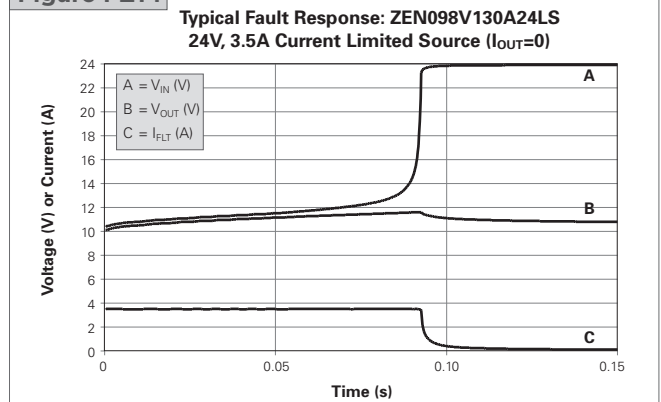


Figure PZ16-PZ23 Basic Operation Examples for PolyZen Devices

Cont'd

Figure PZ15

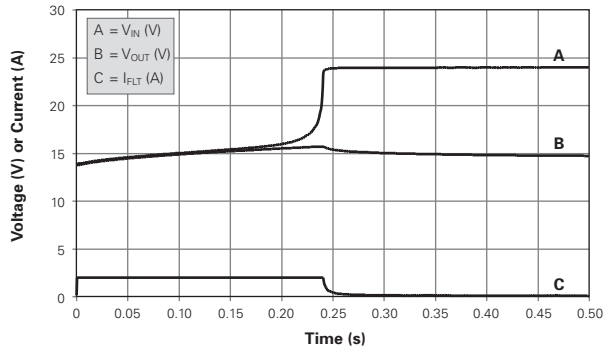
 Typical Fault Response: ZEN132V130A24LS
 24V, 2.0A Current Limited Source ($I_{OUT}=0$)


Figure PZ16

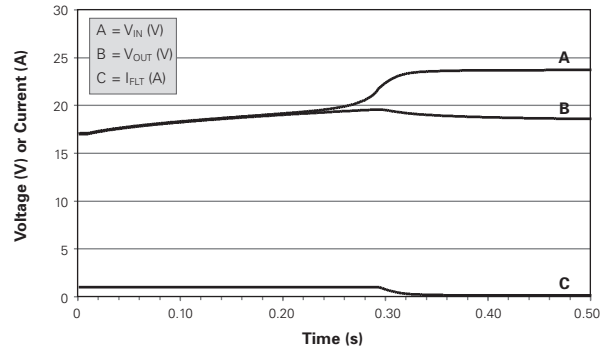
 Typical Fault Response: ZEN164V130A24LS
 24V, 1.0A Current Limited Source ($I_{OUT}=0$)


Figure PZ17

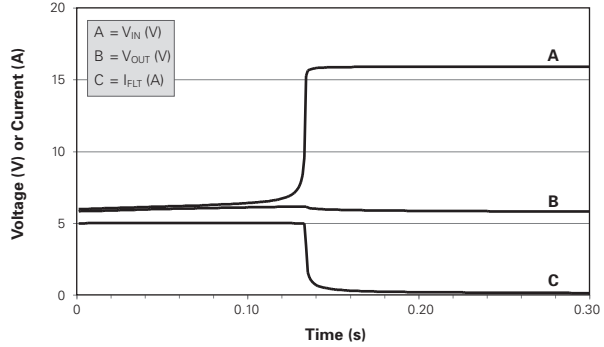
 Typical Fault Response: ZEN056V230A16LS
 16V, 5.0A Current Limited Source ($I_{OUT}=0$)


Figure PZ18

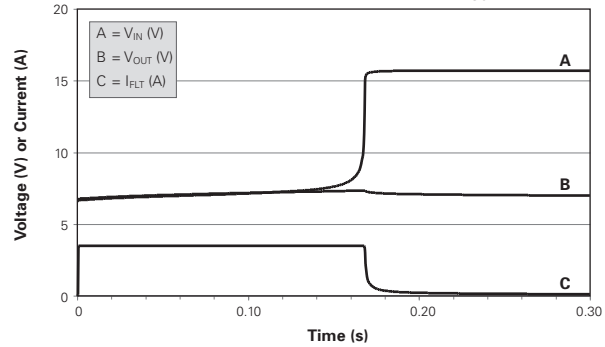
 Typical Fault Response: ZEN065V230A16LS
 16V, 3.5A Current Limited Source ($I_{OUT}=0$)


Figure PZ19

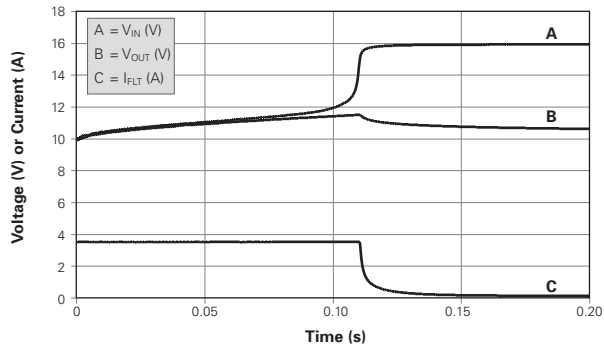
 Typical Fault Response: ZEN098V230A16LS
 16V, 3.5A Current Limited Source ($I_{OUT}=0$)


Figure PZ20

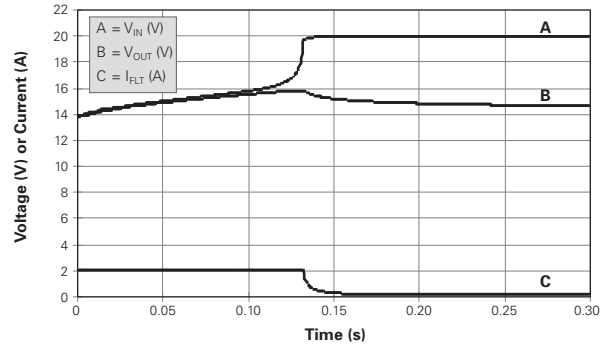
 Typical Fault Response: ZEN132V230A16LS
 20V, 2.0A Current Limited Source ($I_{OUT}=0$)


Figure PZ21

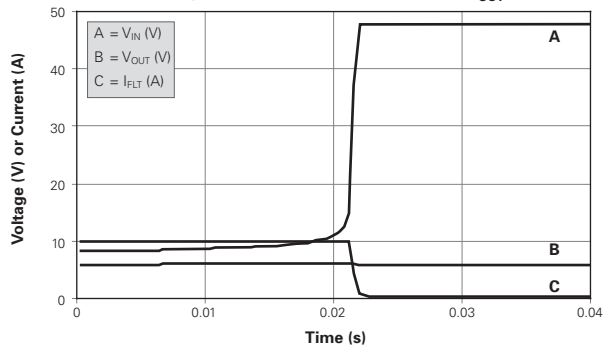
 Typical Fault Response: ZEN056V075A48LS
 48V, 10.0A Current Limited Source ($I_{OUT}=0$)


Figure PZ22

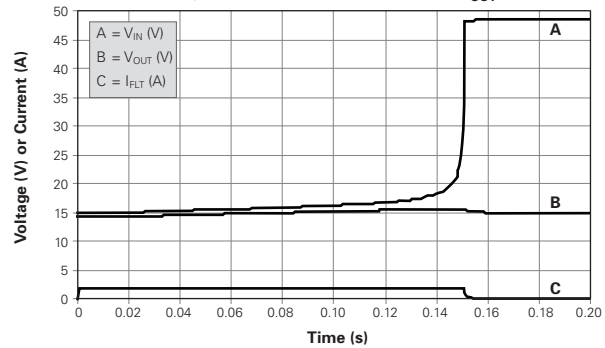
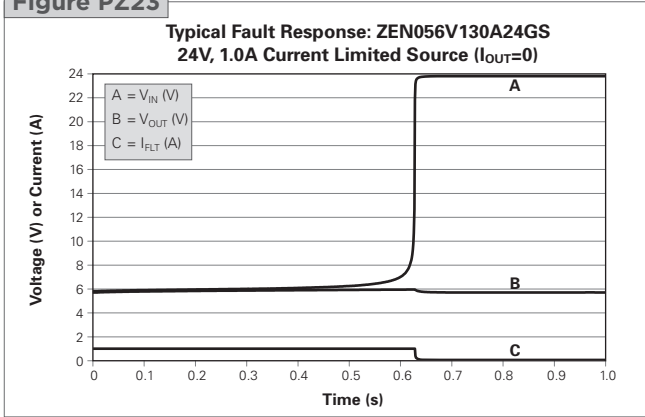
 Typical Fault Response: ZEN132V075A48LS
 48V, 2.0A Current Limited Source ($I_{OUT}=0$)


Figure PZ23


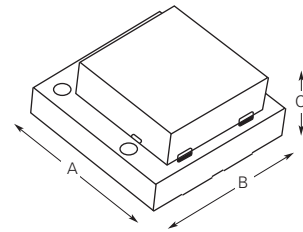
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Table PZ4 Packaging and Marking Information for PolyZen Devices

Part Number	Bag Quantity	Tape & Reel Quantity	Standard Package
ZENxxxVyyyAzzLS	-	3,000	15,000
ZENxxxVyyyAzzGS	-	4,000	20,000

Table PZ5 Dimensions for PolyZen Devices in Millimeters (Inches)
ZENxxxVyyyAzzLS Devices

	A		B		C	
	Min.	Max.	Min.	Max.	Min.	Max.
mm	3.85	4.15	3.85	4.15	1.40	2.00
inch	(0.152)	(0.163)	(0.152)	(0.163)	(0.055)	(0.081)


ZENxxxVyyyAzzGS Devices

	L		W		H	
	Min.	Max.	Min.	Max.	Min.	Max.
mm	3.85	4.15	3.85	4.15	1.16	1.25
inch	(0.152)	(0.163)	(0.152)	(0.163)	(0.046)	(0.049)

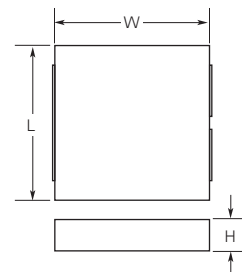
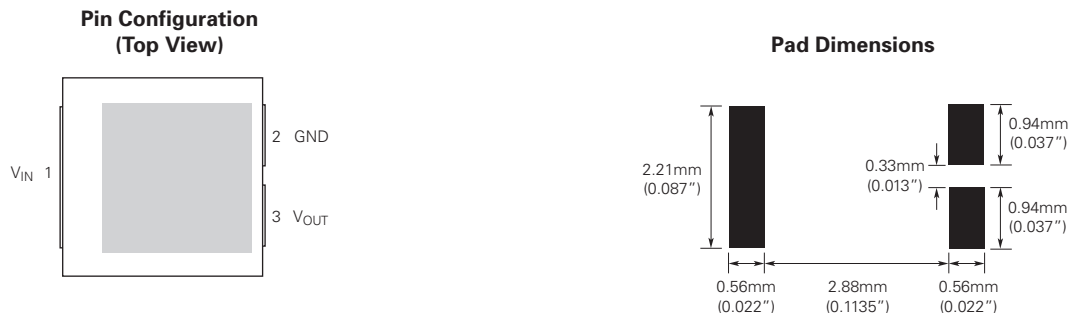


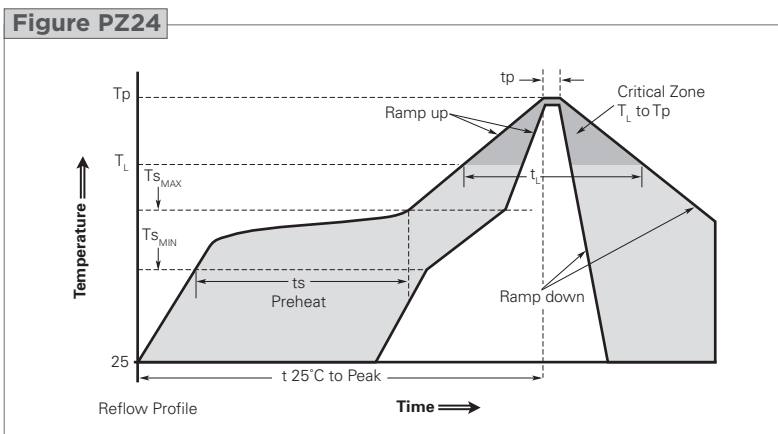
Table PZ6 Pad Layout and Configuration Information for PolyZen Devices

Pin Number	Pin Name	Pin Function
1	V _{IN}	V _{IN} = Protected input to Zener diode
2	GND	GND = Ground
3	V _{OUT}	V _{OUT} = Zener regulated voltage output


Solder Reflow and Rework Recommendation for PolyZen Devices
Classification Reflow Profiles

Profile Feature	Pb-Free Assembly
Average ramp up rate (T_SMAX to T_p)	3°C/second max.
Preheat	
• Temperature min. (T _S MIN)	150°C
• Temperature max. (T _S MAX)	200°C
• Time (t _S MIN to t _S MAX)	60-180 seconds
Time maintained above:	
• Temperature (T _L)	217°C
• Time (t _L)	60-150 seconds
Peak/Classification temperature (T_p)	260°C
Time within 5°C of actual peak temperature	
Time (t _p)	20-40 seconds
Ramp down rate	6°C/second max.
Time 25°C to peak temperature	8 minutes max.

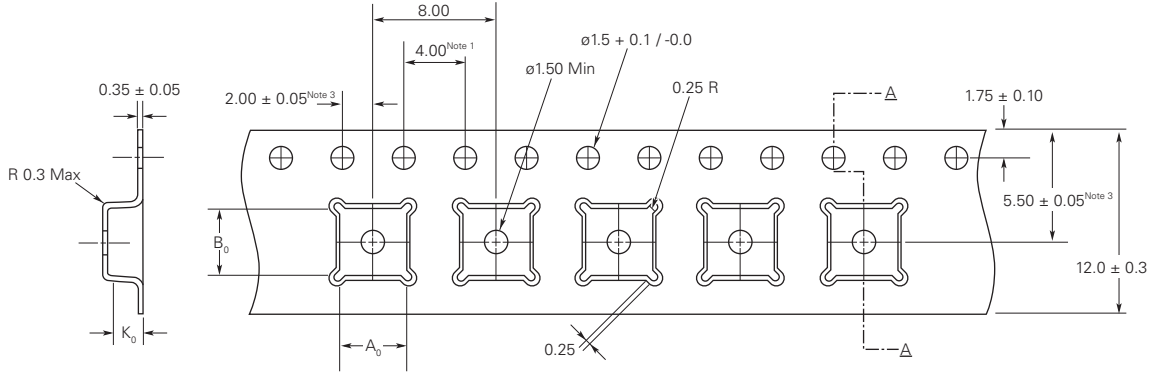
Note: All temperatures refer to topside of the package, measured on the package body surface.



Tape and Reel Specifications for PolyZen Devices (in Millimeters)

Figure PZ25 EIA Referenced Taped Component Dimensions for PolyZen Devices (in Millimeters)

Description	ZENxxxVyyyAzzLS Devices	ZENxxxVyyyAzzGS Devices
A ₀	4.35	4.35
B ₀	4.35	4.35
K ₀	2.30	1.80

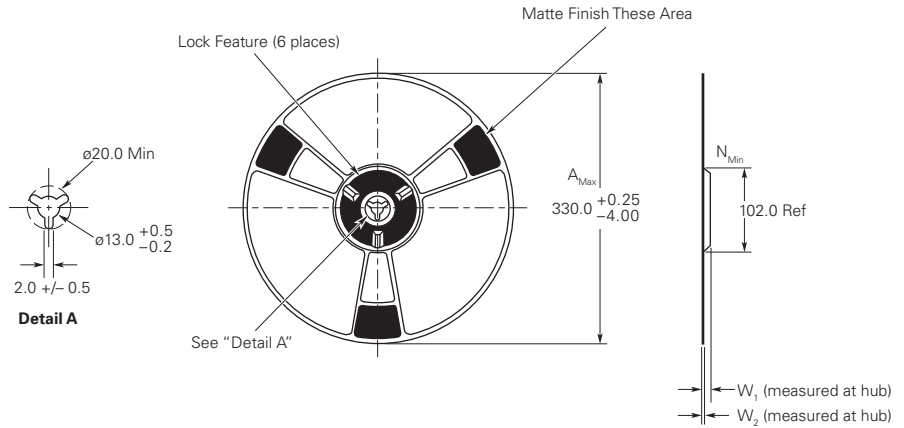


Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2
2. Camber in compliance with EIA 481
3. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole

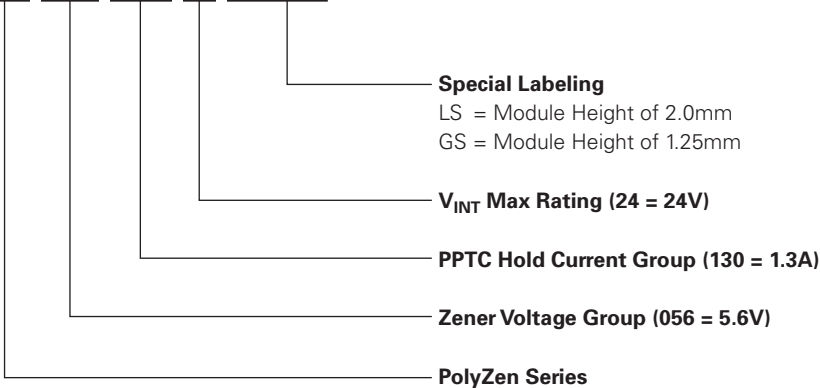
Figure PZ26 Reel Dimensions for PolyZen Devices (in Millimeters)

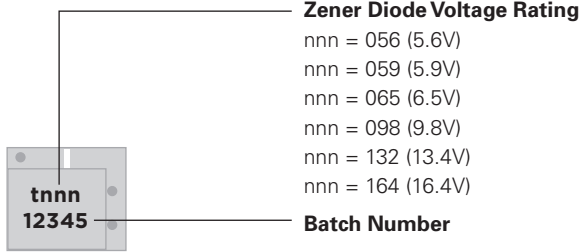
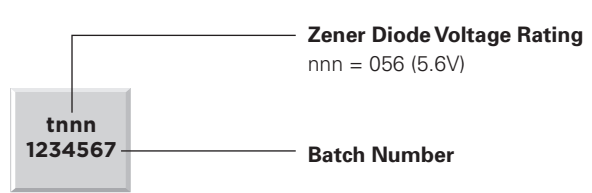
Description	Dimension (mm)
A _{Max}	330
N _{Min}	102
W ₁	8.4
W ₂	11.1



Part Numbering System for PolyZen Devices

ZEN 056V 130A 24 LS & GS



Part Marking System for PolyZen Devices
ZENxxxVyyyAzzLS Devices

ZENxxxVyyyAzzGS Devices

Warning :

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